

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# 2N5400

**Preferred Device** 

# **Amplifier Transistors**

# **PNP Silicon**

#### **Features**

• Pb-Free Packages are Available\*

### **MAXIMUM RATINGS**

Rating	Symbol	Value	e Unit	
Collector – Emitter Voltage	V <sub>CEO</sub>	120	Vdc	
Collector - Base Voltage	V <sub>CBO</sub>	130	Vdc	
Emitter – Base Voltage	V <sub>EBO</sub>	5.0	Vdc	
Collector Current – Continuous	I <sub>C</sub>	600	mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

#### THERMAL CHARACTERISTICS

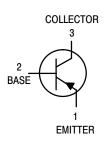
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

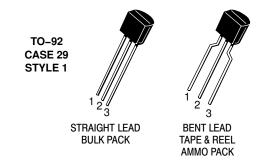
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



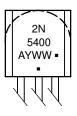
## ON Semiconductor®

#### http://onsemi.com





## **MARKING DIAGRAM**



A = Assembly Location

Y = Year

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## 2N5400

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	_	•	•	
Collector-Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	120	_	Vdc
Collector–Base Breakdown Voltage ( $I_C = 100 \mu Adc, I_E = 0$ )	V <sub>(BR)CBO</sub>	130	_	Vdc
Emitter-Base Breakdown Voltage $(I_E=10~\mu\text{Adc},~I_C=0)$	V <sub>(BR)EBO</sub>	5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	I <sub>CBO</sub>	- -	100 100	nAdc μAdc
Emitter Cutoff Current $(V_{EB} = 3.0 \text{ Vdc}, I_{C} = 0)$	I <sub>EBO</sub>	-	50	nAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ( $I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ )	h <sub>FE</sub>	30	_	-
$(I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$		40	180	
$(I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$		40	_	
Collector–Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	- -	0.2 0.5	Vdc
$\begin{aligned} \text{Base-Emitter Saturation Voltage} \\ & (I_{\text{C}} = 10 \text{ mAdc}, I_{\text{B}} = 1.0 \text{ mAdc}) \\ & (I_{\text{C}} = 50 \text{ mAdc}, I_{\text{B}} = 5.0 \text{ mAdc}) \end{aligned}$	V <sub>BE(sat)</sub>	- -	1.0 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current-Gain — Bandwidth Product $(I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz})$	f <sub>T</sub>	100	400	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )	C <sub>obo</sub>	-	6.0	pF
Small–Signal Current Gain ( $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ )	h <sub>fe</sub>	30	200	_
Noise Figure $(I_C = 250 \ \mu Adc, \ V_{CE} = 5.0 \ Vdc, \ R_S = 1.0 \ k\Omega, \ f = 1.0 \ kHz)$	NF	-	8.0	dB

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
2N5400	TO-92	5000 Unit / Bulk
2N5400G	TO-92 (Pb-Free)	5000 Unit / Bulk
2N5400RLRP	TO-92	2000 Tape & Reel
2N5400RLRPG	TO-92 (Pb-Free)	2000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

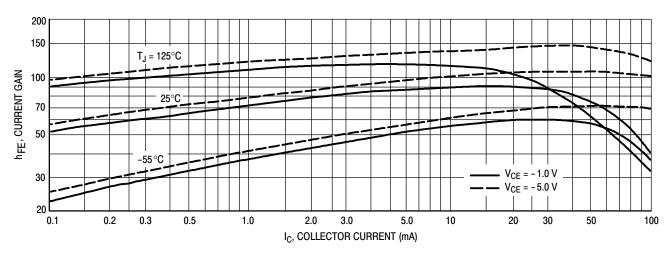


Figure 1. DC Current Gain

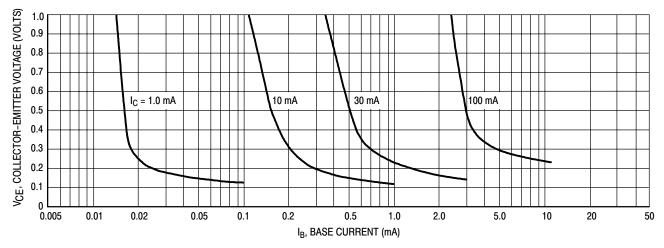


Figure 2. Collector Saturation Region

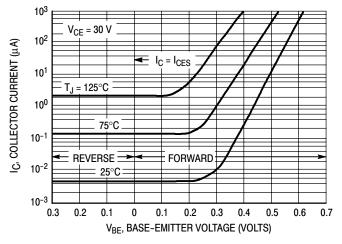


Figure 3. Collector Cut-Off Region

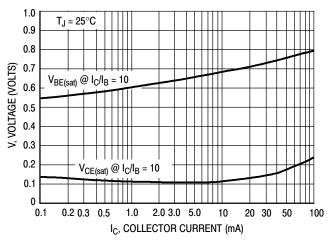
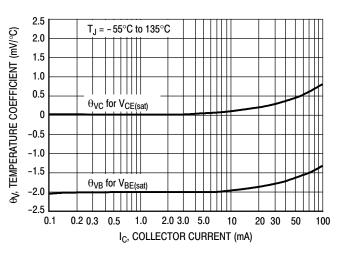
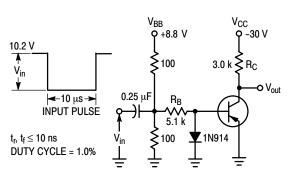


Figure 4. "On" Voltages



**Figure 5. Temperature Coefficients** 



Values Shown are for I<sub>C</sub> @ 10 mA

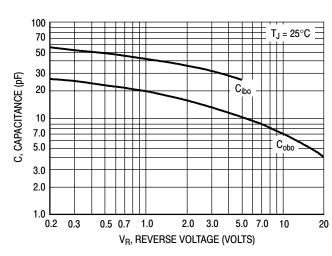


Figure 7. Capacitances

# Figure 6. Switching Time Test Circuit

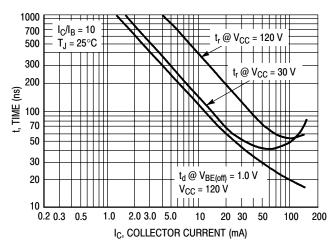


Figure 8. Turn-On Time

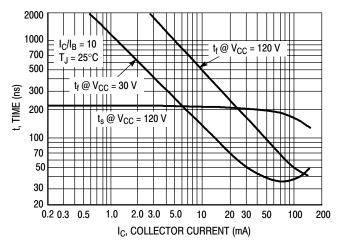
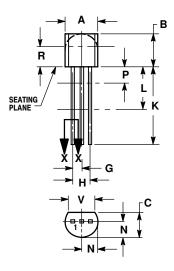


Figure 9. Turn-Off Time

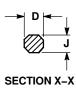
#### 2N5400

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



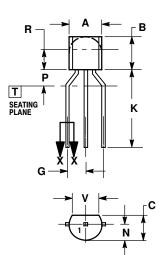
STRAIGHT LEAD **BULK PACK** 



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
  IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
v	0 135		3 43	



**BENT LEAD** TAPE & REEL AMMO PACK



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION:
- MILLIMETERS.
- DIMENSION R IS UNCONTROLLED.

  LEAD DIMENSION IS UNCONTROLLED IN
- P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93	-	
٧	3.43		

PIN 1. EMITTER

BASE

COLLECTOR

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